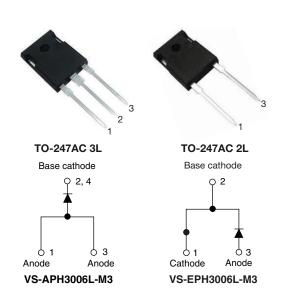


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Vishay Semiconductors

Hyperfast Rectifier, 30 A FRED Pt®



PRIMARY CHARACTERISTICS						
I _{F(AV)} 30 A						
V _R	600 V					
V _F at I _F	1.4 V					
t _{rr} typ.	27 ns					
T _J max.	175 °C					
Package	TO-247AC 3L, TO-247AC 2L					
Circuit configuration	Single					

FEATURES

- · Low forward voltage drop
- Hyperfast soft recovery time
- 175 °C operating junction temperature
- Designed and qualified according to commercial qualification

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ROHS COMPLIANT HALOGEN

FREE

DESCRIPTION / APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Repetitive peak reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 112 °C	30	Λ		
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	220	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage	V _F	I _F = 30 A	-	2.0	2.65	V	
		I _F = 30 A, T _J = 150 °C	-	1.4	1.8		
Devene leekees euwent		$V_R = V_R$ rated	-	0.02	30		
Reverse leakage current I _R		T _J = 150 °C, V _R = V _R rated	-	-	300	μΑ	
Junction capacitance	C _T	V _R = 600 V	-	20	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH	



VS-APH3006L-M3, VS-EPH3006L-M3

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 3$		-	26	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	26	-	ns
		T _J = 125 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	70	-	
Peak recovery current		T _J = 25 °C		-	3.5	-	А
	I _{RRM}	T _J = 125 °C		-	7.6	-	
Reverse recovery charge	0	T _J = 25 °C		-	50	-	nC
	Q _{rr}	T _J = 125 °C		-	280	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	0.7	1.1	°C/W
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	5.5	-	g
Weight			-	0.2	-	OZ.
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC 3L	APH3006L			
		Case style TO-247AC 2L		EPH3006L		



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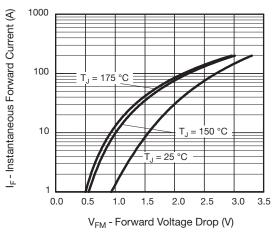


Fig. 1 - Typical Forward Voltage Drop Characteristics

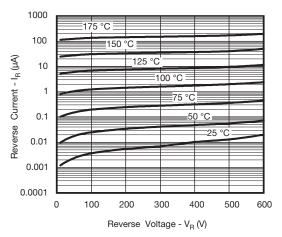


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

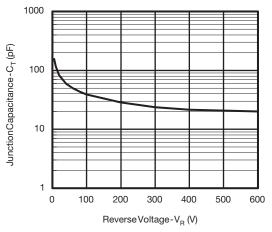


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

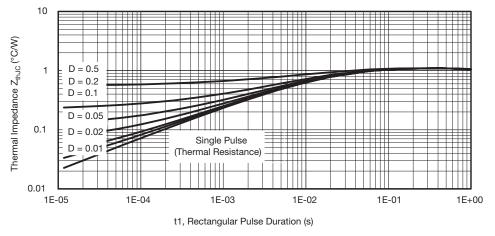


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

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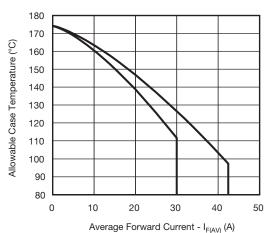


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

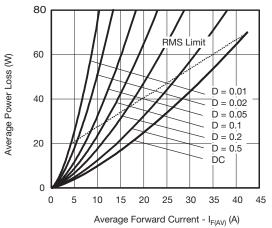


Fig. 6 - Forward Power Loss Characteristics

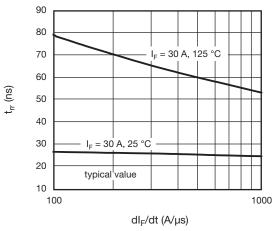


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

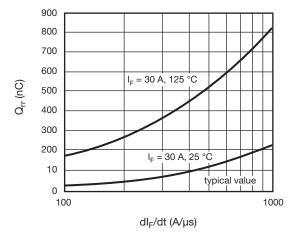
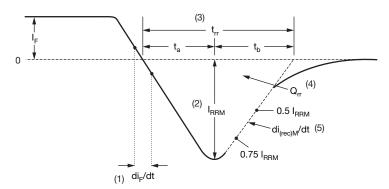


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

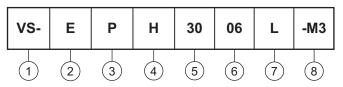
Fig. 9 - Reverse Recovery Waveform and Definitions

VS-APH3006L-M3, VS-EPH3006L-M3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- • A = single diode

• E = single diode

3 - P = TO-247

H = hyperfast recovery time

- Current code (30 = 30 A)

6 - Voltage code (06 = 600 V)

7 - L = long lead

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and termination lead (Pb)-free

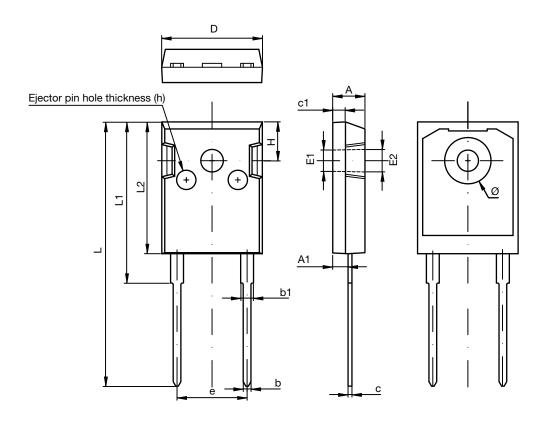
ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-APH3006L-M3	30	300	Antistatic plastic tube			
VS-EPH3006L-M3	30	300	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-247AC 3L	www.vishay.com/doc?95599			
Dimensions	TO-247AC 2L	www.vishay.com/doc?95598			
Part marking information	TO-247AC 3L	www.vishay.com/doc?95593			
	TO-247AC 2L	www.vishay.com/doc?95592			
SPICE model		www.vishay.com/doc?96580			

Vishay Semiconductors

TO-247AD 2L

DIMENSIONS in millimeters



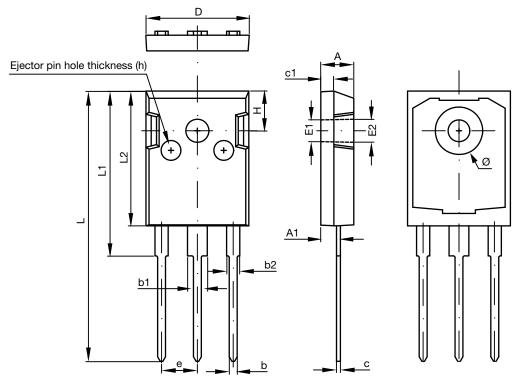
SYMBOL	DIMENSIONS I	N MILLIMETERS	DIMENSION	S IN INCHES
STINIBUL	MIN.	MAX.	MIN.	MAX.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.50	0 Ref.	0.138 Ref.	
E2	3.60	0 Ref.	0.142 Ref.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Ø	7.100	7.300	0.280	0.287
е	10.900 Typ.		0.429 Typ.	
Н	5.98	5.980 Typ.		5 Тур.
h	0.000	0.300	0.000	0.012



Vishay Semiconductors

TO-247AD 3L

DIMENSIONS in millimeters



SYMBOL	DIMENSIONS	IN MILLIMETERS	DIMENSION	S IN INCHES	
STWIBUL	MIN.	MAX.	MIN.	MAX.	
Α	4.850	5.150	0.191	0.200	
A1	2.200	2.600	0.087	0.102	
b	1.000	1.400	0.039	0.055	
b1	2.800	3.200	0.110	0.126	
b2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.900	2.100	0.075	0.083	
D	15.450	15.750	0.608	0.620	
E1	3.500 Ref.		0.13	8 Ref.	
E2	3.60	00 Ref.	0.142	Ref.	
L	40.900	41.300	1.610	1.626	
L1	24.800	25.100	0.976	0.988	
L2	20.300	20.600	0.799	0.811	
Ø	7.100	7.300	0.280	0.287	
е	5.450 Typ.		0.21	5 Тур.	
Н	5.980 Typ.		0.23	5 Тур.	
h	0.000	0.300	0.000	0.012	



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